

Gate Drive Technical Manual

P100191

This document is suitable for use with all Amantys Gate Drives that support configuration via Power Insight. These include,

AP12A On-module 1200V Gate Drive

AP17A On-module 1700V Gate Drive

AV17 On-module 1700V Gate Drive for 2-6 nHPD², LinPak, LV100 or XHP2/3 modules

AP33A On-module 3300V Gate Drive (also configured as AP12G and AP17G)

AP0xB Dual Core Baseboard with 1700V or 3300V Module Interface Card

AD00XA8 Off-module Single Gate Drive with 1700V or 3300V Module Interface Card

AV33 On-module 3300V Gate Drive for 2-6 nHPD², LinPak, LV100 or XHP2/3 modules

AP00J Off-module Gate Drive with 4500V or 6500V Module Interface Card

Where features are specific to a particular gate drive configuration they will be identified by the part numbers and revisions of the programmable devices. For further information refer to *Section 3. Identifying the Gate Drive Version and Revision*.

Refer to the product datasheet for specific voltage variants, 1200V, 1700V and 3300V, as the same base printed circuit board may be used with different components fitted.

This document does not describe Power Insight in detail. Please refer to alternative documentation and specific gate drive datasheets for further information.

Note: AE00NA8S Dual On-Module Gate Drive for single nHPD² and LinPak modules does not have user configurable parameters, however some of the protection mechanisms described in this manual are implemented.

Important

The information contained herein is intended exclusively for qualified engineers who are experienced with, and trained in, working with high voltage apparatus which involves risk to life. Strict compliance with all relevant safety regulations for the target application is essential.

Any handling of electronic devices is subject to the general specifications for protecting electrostatic sensitive devices according to international standard IEC 747-1, Chapter IX or European standard EN 100015 (i.e. the workplace, tool, operating environment, etc. must comply with these standards). Failure to comply may lead to the product becoming damaged.

WARNING: High voltage equipment - for use by trained personnel only.



Failure to observe electrical shock precautions while the equipment is in operation may result in personal injury, electrical shock damage to, or destruction of components of this equipment.

CAUTION: When handling the Gate Drive and the IGBT module, observe electro-static precautions. If these precautions are not taken, permanent damage to the components may result.



Technical Support

For technical support please visit www.amantys.com.

For IGBT module data refer to the manufacturer's data sheet.

Quality Control

The gate drive is manufactured according to ISO9001:2000 quality standards.

Product Customisation

Contact Amantys Power Electronics Ltd to discuss any product customisation requirements. Contact details can be found on the website.

Legal Disclaimer

This document describes devices but cannot promise to deliver any specific characteristics. No warranty or guarantee is given - either expressly or implicitly - regarding delivery, performance or suitability.

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1 Introduction

Amantys Gate Drives are high performance, single channel drivers suitable for high-power IGBT modules. They are configurable and capable of driving modules from all leading IGBT manufacturers without the need to add external gate resistors and capacitors giving greater design and reuse flexibility.

This document is suitable for use with both on-module gate drives, such as the 3300V Gate Drive for 190x140mm and 140x130mm IGBTs (see Figure 1), and the Core Gate Drive and its associated interface cards.

In its simplest form a gate drive has one input to turn the IGBT on and off, and one output to acknowledge the switching edge and signal a fault. Various status and fault signalling protocols are supported. For high voltage IGBTs (1700V and above) this interface typically uses fibre-optic transceivers. Power is provided by a pair of wires at 15V or 24V and the gate drive features an isolated DC-DC converter to provide the local supplies.

The output drive stage is a traditional voltage source with configurable turn-on, turn-off and soft-turn-off resistors. Some gate drive configurations feature an extra turn-off resistor that is selected when the DC link is above a programmed threshold. This is useful for situations where the DC link can rise for a short time (such as under low load or braking) and it prevents unnecessary stress on the clamping components.

Status LEDs are provided to facilitate identification of normal operation and fault conditions. Refer to the relevant datasheet for information about what the LEDs mean.

As Amantys products are digital gate drives, they feature a range of programmable registers and configuration options to suit a variety of target IGBT modules and applications. The user should take care not to accidentally disable the fault protection features.

Amantys gate drives have interfaces to allow programming of the complex programmable logic device (CPLD) and the micro-controller in the factory, but user updates can be made in the field over the fibre-optic interface using a Power Insight Adapter and the Power Insight Configurator software tool that runs on any Windows PC.

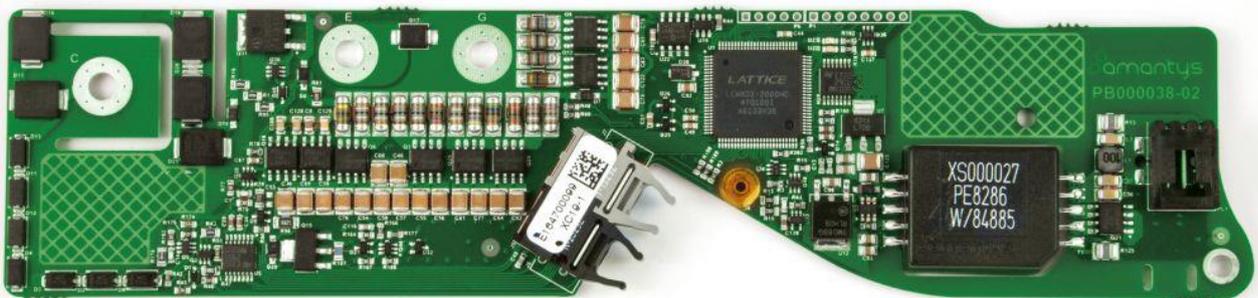


Figure 1. 3300V On-module Gate Drive

2 Architecture

For an on-module gate drive, all components are mounted on a single printed circuit board (PCB) as shown in Figure 2.

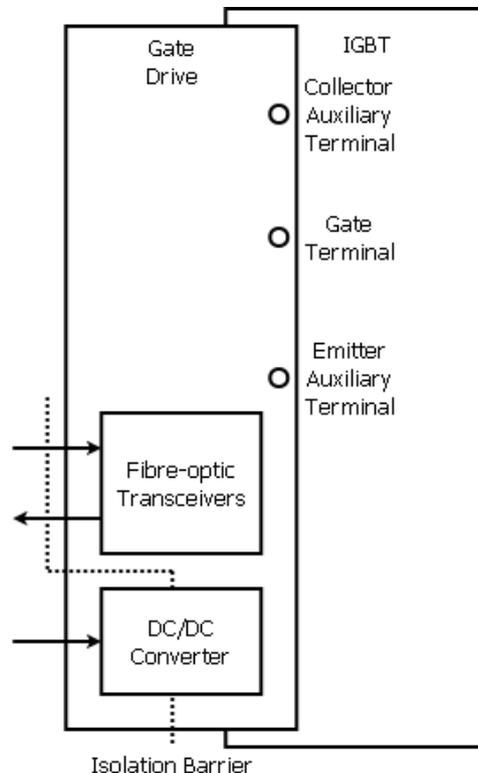


Figure 2. On-module Gate Drive Overview

The architecture for an assembly that uses the Core Gate Drive is the same but distributed over a number of circuit boards. The hardware features for both solutions are the same except that the on-module gate drive does not have an input for an NTC temperature sensor.

The Core Gate Drive is the main functional part of the gate drive and is coupled with additional circuitry close to the IGBT module known as a Module Interface Card (MIC). The Core Gate Drive contains no power supply or signal isolation, so a suitable isolated DC-DC converter and signal isolators (fibre-optic transceivers, opto-couplers or digital isolators) are required. These are external to the Core Gate Drive to allow flexibility in voltage range, board layout and power dissipation. Typically, these are mounted on a baseboard or off-module carrier board. Amantys will supply an assembly comprising multiple boards and cables as shown in Figure 3.

The AD00XA8 gate drive is an off-module solution designed to be compatible with other gate drives in the market. It has some unique features, notably a wide-ranging (14V to 30V) input power supply, di/dt protection and short pulse protection. The additional configuration parameters are described in the following sections.

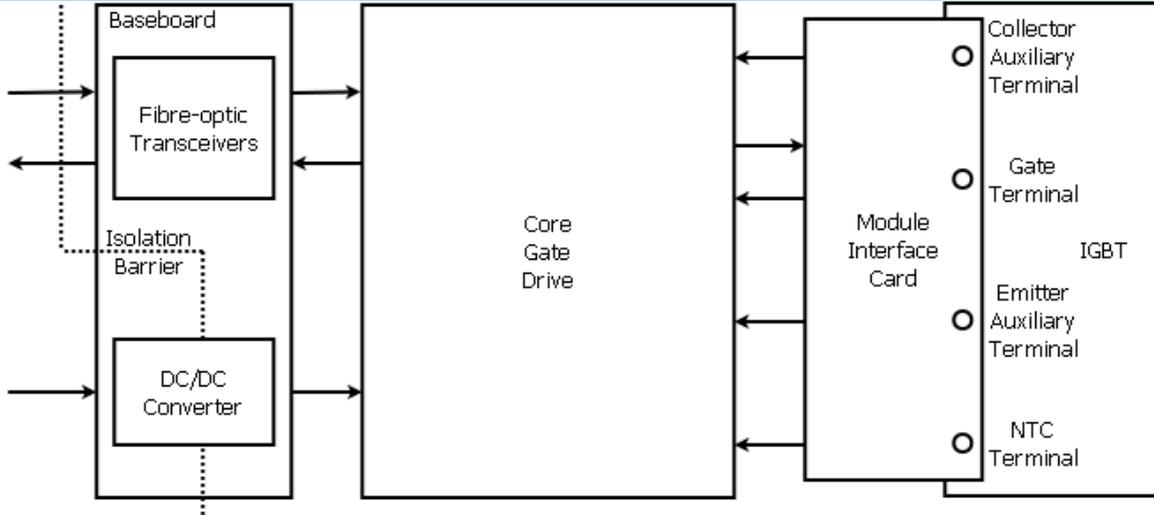


Figure 3. Single Channel Core Gate Drive with Baseboard showing Isolation Barrier and Module Interface Card

For on-module gate drives for nHPD², LinPak, LV100 and XHP2/3 the arrangement is as shown in Figure 4.

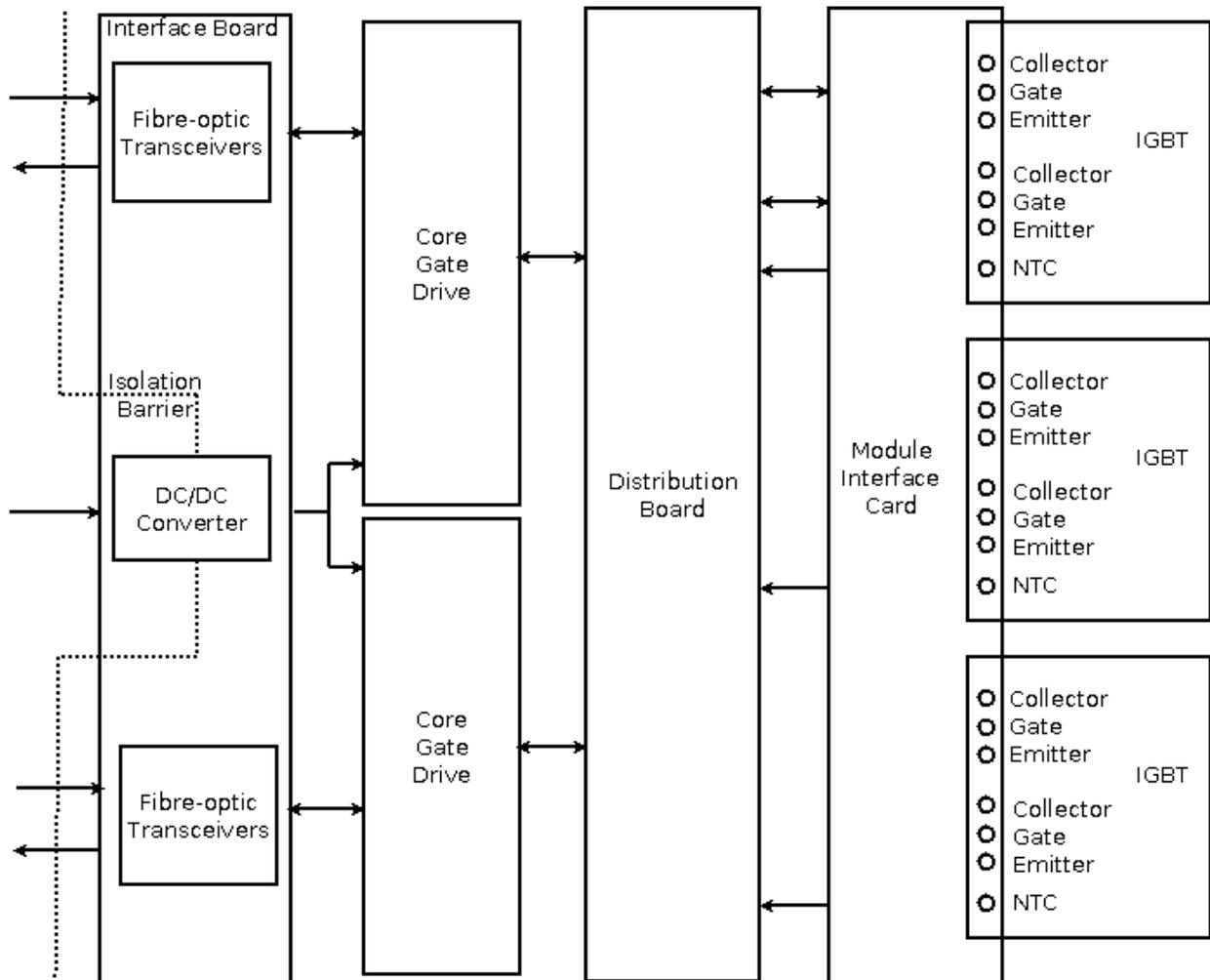


Figure 4. Two Core Gate Drives with Distribution Board and Module Interface Cards to Parallel IGBTs

3 Identifying the Gate Drive Version and Revision

The Amantys Gate Drive is designed to be used with, and configured by, the [Power Insight Configurator](#). The following picture is a screen shot showing the Diagnostics tab for the gate drive connected to port 0 of the Power Insight Adapter. For support purposes it may be helpful to write this information to a text file using the “Save to Text File” button provided.

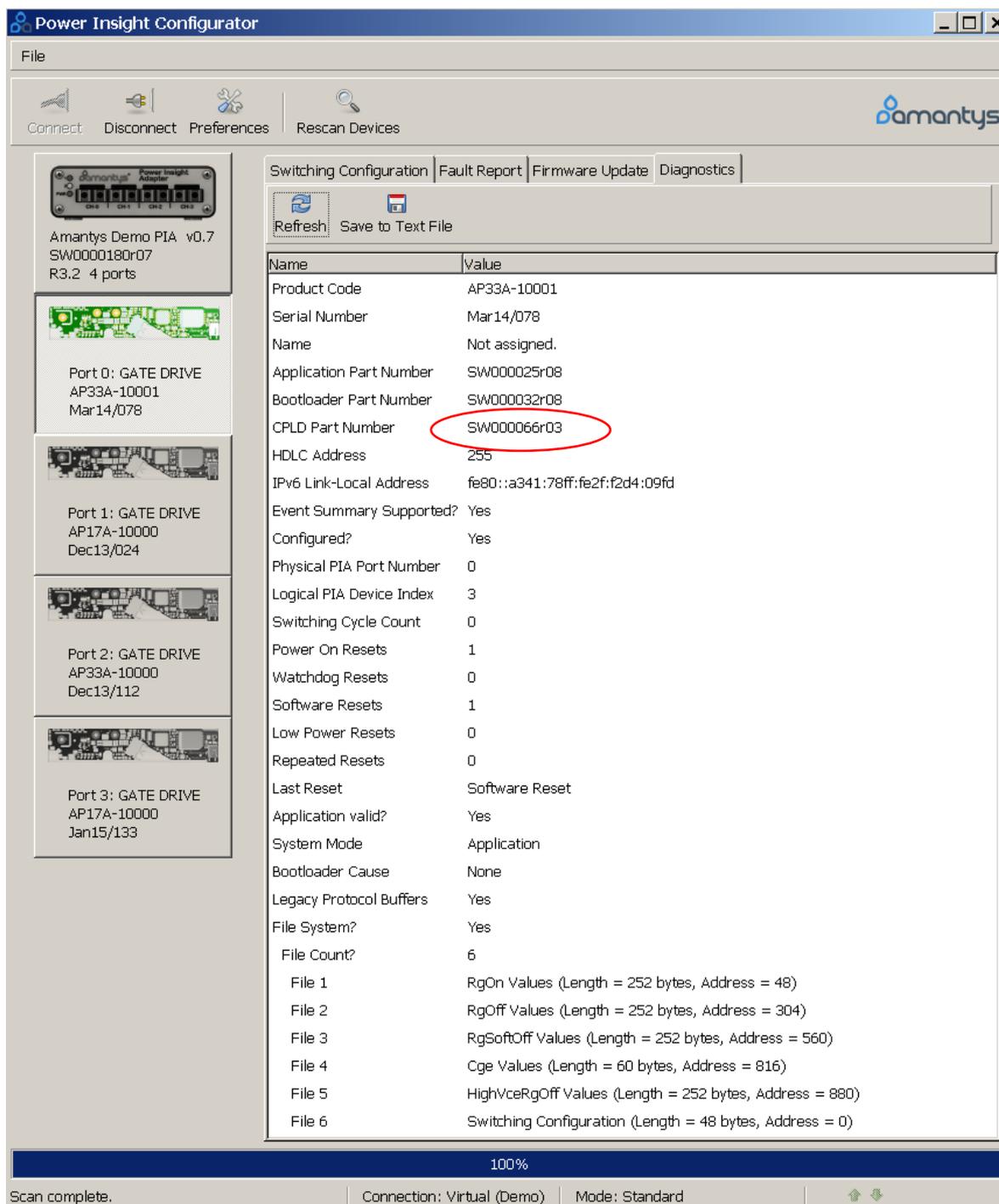


Figure 5. Screen-shot of the Power Insight Configurator, Gate Drive Diagnostics tab

To identify features of the hardware it is useful to make a note of the “CPLD Part Number” and revision which will be as shown as in Figure 5. The Configurator reads this information and from it decides which configuration parameters to show in the “Switching Configuration” tab.

If the Configurator reports that the gate drive is not recognised, then it is possible that the CPLD is a newer version than supported by the tool. In this case make sure the latest version is installed and if there is still a problem the Configurator database can be updated with a new file from the Amantys website. Refer to the User Guide supplied with the Power Insight Configurator for further details.

All configurable parameters on the gate drive can be set by selecting the Switching Configuration tab.

Configurable parameters in this document are presented for ease of identification as follows:

Parameter Name

A full list of available parameters for each gate drive can be found at the end of this document (Appendices), however new configuration parameters may be introduced periodically so please refer to the Power Insight Configurator for the most up-to-date list.

4 Gate Drive Overview

A typical Amantys gate drive contains the features shown in the block diagram, Figure 6. The NTC terminal connection is not always available. The AD00XA8 gate drive has an additional Power Emitter terminal for sensing di/dt.

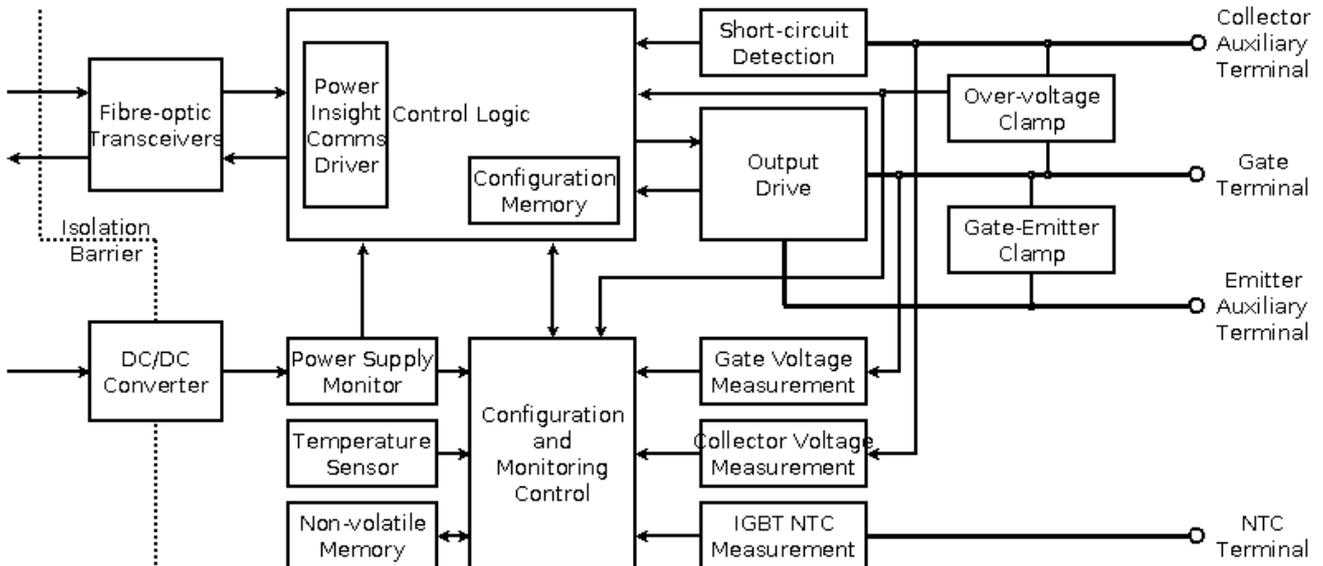


Figure 6. Gate Drive Block Diagram

4.1 Connecting to an IGBT

It is preferable if the gate drive can be located as close as possible to the gate and emitter connections of the IGBT module to minimise stray inductance and maximise control of the IGBT. Normally the on-module gate drive or module interface card (MIC) is mounted directly on the IGBT using the screw terminals provided.

If an on-module gate drive is connected to an IGBT module with wires, care must be taken to ensure the wires are as short as possible (typically less than 100mm) and maximum setting for the desaturation filter (see 8.4) is recommended as the gate drive is liable to pick-up more interference.

The architecture for the Core Gate Drive gate drive allows it to be mounted at a distance from the IGBT module. It also allows for parallel operation where one driver controls multiple IGBT modules. In this case the cable connection can be longer, typically up to 500mm, and the cable has been designed to minimise the loop inductance and therefore susceptibility to noise pickup.

To connect the Core Gate Drive to an IGBT, first mount the Module Interface Card (MIC) on to the IGBT using the screw terminals provided. Then connect the ribbon cables or distribution board, making sure there is no violation of creepage and clearance requirements. The Core Gate Drives, mounted on a motherboard, can then be located in an appropriate place in the converter and connected. Alternatively two Core Gate Drives are mounted on the Distribution board with an appropriate power and optical interface.

It is recommended to use screws with internal spring shake-proof washers to connect the gate drive or MIC to the IGBT module. This prevents loose washers from finding their way into the power assembly. Alternatively a combination of plain and spring washers are acceptable. In some cases washers may be required underneath the gate drive or MIC to ensure there is sufficient mechanical

clearance between the IGBT module and any tall components on the underside of the board as shown in Figure 7.

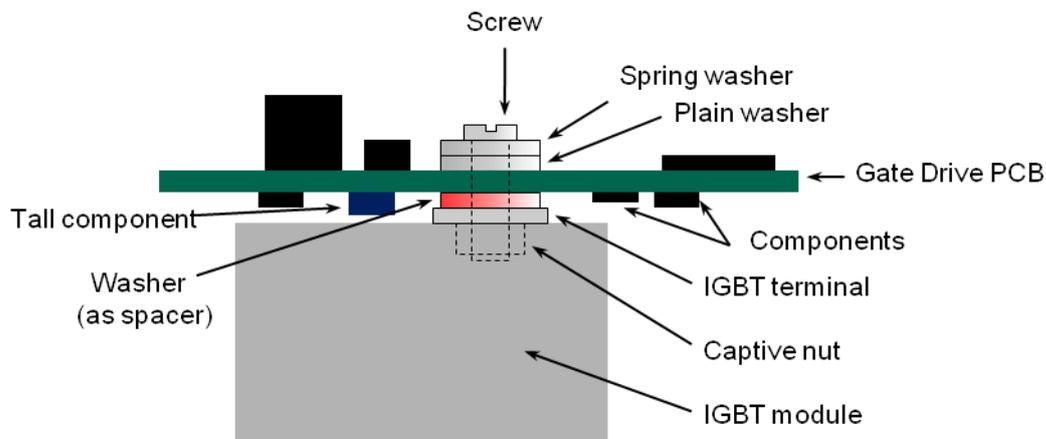


Figure 7. Gate Drive mounted on IGBT module showing spacer to avoid interference with tall components

Note: Carefully review the IGBT module mounting points to avoid interference with the components on the underside of the gate drive or MIC. Do not over-tighten screws, and use the torque setting recommended by the IGBT module vendor.

4.2 Power Supply

The power supply input is either 15V or 24V depending on the configuration ordered. Refer to specific datasheets (obtained from Amantys or downloaded from the website) for typical current consumption. The quiescent power dissipation is about 1.65W per gate drive and the total power required is proportional to the switching frequency and IGBT gate charge.

The total power dissipation should be less than the value in the datasheet and can be calculated as follows,

$$P = 1.65 + Q_G \cdot f_{sw} \cdot \Delta V_{gg}$$

Where, P = power, Q_G = gate charge (from the IGBT datasheet), f_{sw} = switching frequency and ΔV_{gg} is the gate voltage swing, typically 25V (i.e. from -10V to 15V).

4.3 Fibre-optic transceivers

Broadcom (Avago) or Firecomms transceivers are used to implement the fibre-optic interface.

The Broadcom transmitter is an AFBR-1529Z and the receiver an AFBR-2529Z. Refer to Broadcom documents for details and interfacing information [1].

The Firecomms transmitter is an FT10MHLR and the receiver an FR50MHIR. Refer to Firecomms documents for details and interfacing information [2].

4.4 Measurement

For accurate V_{CE} measurement the gate drive or Module Interface Card features a 0.1% tolerance resistor chain. This allows the IGBT saturation voltage, $V_{CE(on)}$, and the diode forward voltage drop, V_F , to be measured with a high degree of accuracy (better than 10mV) in the range -6.76V to

+10.97V. This measurement is available 50 μ s after the IGBT is turned on and this time is fixed in the gate drive hardware.

The DC link voltage, i.e. the voltage across the IGBT when off, $V_{CE(off)}$, can also be measured up to the voltage rating of the IGBT. Comparators with programmable references can be used for desaturation detection during turn-on, and to measure the voltage across the IGBT during the first 50 μ s.

To sense di/dt or current, the voltage across the emitter stray inductance may be measured. This requires a connection to the power emitter as well as the auxiliary emitter. Functionality is provided on some gate drives to allow specific customer features to be implemented, but di/dt and current measurement is not enabled (or required) by default.

Some IGBT modules include a negative temperature coefficient (NTC) thermistor connected to a dedicated terminal and referenced to the auxiliary emitter. This connection is included on the Core Gate Drive.

4.5 Immunity to high dv/dt and di/dt

High dv/dt when an IGBT switches will cause a current to flow between the primary and secondary of the isolating transformer. To minimise this, the transformer capacitance is very low. High dv/dt can also cause coupling by capacitance into high value resistors (M Ω). By careful layout of the on-module gate drive PCBs such resistors are shielded from nearby busbars, and digital filters are used on any signals that monitor the resistor chains. This is not so much of a problem for the the AD00XA8 gate drive and cores mounted on a baseboard which are off-module and can be located away from sources of dv/dt .

Regarding di/dt , there is always the chance of magnetic coupling into any loops of wire on or off the gate drive boards. The only solution is to keep the loop area as small as possible, either by routing tracks close together or close to a ground plane on the board. Digital noise filters are used to remove signals generated by short pulses of magnetic energy coupled into the gate drive circuits, such as di/dt comparators.

4.6 EMC compliance

Amantys gate drives are tested against railway and industrial motor drive standards for immunity and to ensure they are not a significant source of radiated emissions. By far the most significant source of emissions is the IGBT itself switching. This can cause radiated emissions from any cables that exit the gate drive boards, the most significant of which is usually the power supply cable.

The railways standards require that the converter is tested for EMC compliance, but it is not always necessary to test at the gate drive component level. Emissions from the gate drive and cables will often be contained within the converter enclosure. In order to pass emissions tests on a gate drive that is outside of a converter, some measures are taken (such as an external common-mode choke) to limit the level of emissions. Please refer to the EMC test reports for full details.

5 Fibre-optic Interface

5.1 PWM input

The gate drive responds to the edges of the PWM input signal. A rising edge (light off to on) will turn the IGBT ON, and a falling edge (light on to off) will turn the IGBT OFF.

5.2 Feedback Signalling (Amantys protocol)

When a change in the PWM input is received, an acknowledge signal is sent via the FB/ACK output as shown below. The FB/ACK output pulses LOW to indicate a PWM edge has been received. In the event of a fault the FB/ACK output goes LOW until the fault has been cleared. This scheme is compatible with many industry-standard plug and play gate drives.

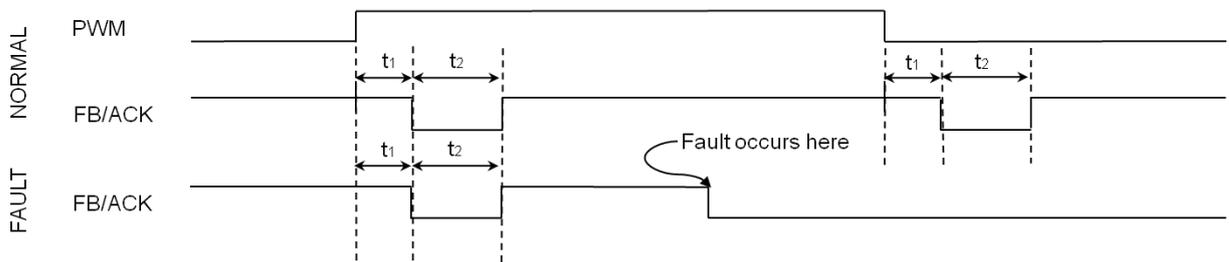


Figure 8. Feedback Protocol Timing Diagram

Parameter	Description	Units	Min	Typ	Max
t_1	PWM to FB/ACK (Compatibility Mode)	ns	-	450	500
t_1	PWM to FB/ACK (Normal Mode)	ns	-	900	1000
t_2	FB/ACK pulse width	ns	500	-	1000

Note: Measurements are made on the pins of the fibre-optic transceivers and do not take into account pulse distortion and delays due to the fibre-optic transceivers.

Table 1. Feedback Protocol Timing Parameters

Specific timing of pulses and pulse widths vary due to pulse width distortion and delays imposed by the fibre-optic transceivers. If the FB/ACK pulse is observed on an oscilloscope after power cycling it will be seen to vary in width as data is transmitted, this is known as Power Insight Compatibility Mode. If the gate drive is switched into Power Insight Normal Mode (or has been programmed to default to Normal Mode) then the width of the FB/ACK pulse will be the same for every switching edge. This is one way to tell which mode the gate drive is in and can be useful when developing communications infrastructure. Note also that the PWM to FB/ACK delay increases in Normal Mode. Further information about Power Insight can be found in 10.

5.3 Other Feedback Protocols

There are a number of other options for FB/ACK signalling, which have been designed to be compatible with OEM equipment. Programmable turn-on and turn-off delays can also be added to match existing gate drives and converter controllers. Please ask Amantys for advice if the default signalling is not suitable. The feedback protocol is set by the following parameter:

Feedback Protocol

The feedback protocol selected is defined in Table 2.

Value	Protocol	Compatible with
0	Amantys Compatibility/Normal Mode	Power Integrations/CT-Concept
1	Custom Mode 1 (gate drive specific)	Refer to Amantys for information
2	Custom Mode 2 (gate drive specific)	Refer to Amantys for information
3	Custom Mode 3 (gate drive specific)	Refer to Amantys for information
4	Custom Mode 4 (gate drive specific)	Refer to Amantys for information
5	Custom Mode 5 (gate drive specific)	Refer to Amantys for information
6	Custom Mode 6 (gate drive specific)	Refer to Amantys for information
7..14	Unused	
15	Internal Signal	Used for debug purposes

Table 2. Feedback protocols

Details of the custom feedback protocols are available on request from Amantys.

When the Feedback Protocol register is set to Internal Signal (value 15) an internal CPLD signal is routed to the FB/ACK output. The source of that signal is selected using the following parameter:

Debug

This is primarily for Amantys use and may be helpful for diagnosing faults in the field. The source of the FB/ACK signal depends on the gate drive configuration and may change, so Amantys will provide a value to program into this register if necessary.

In addition, there is a configuration parameter that is used during factory testing.

Test Config Enable

If this bit is set the red and green LEDs will blink together as a warning. Make sure this bit is set to 0 at all times.

5.4 Fibre-optic drive current level

The following parameter can be used to set the fibre-optic transceiver drive current level. For longest life-time the current should be as low as possible allowing for the length of the optical fibre and for ageing of the transmitter. Values of around 3mA are recommended.

Fibre Drive Current

The range is 1.82mA to 6.37mA in 5 steps. At end-of-life it might be advantageous to increase the drive current, but this may also accelerate wear-out.

6 Drive Stage

The output drive stage is capable of sourcing and sinking current up to a maximum of approximately 30A, determined by the gate resistor settings and output MOSFETs. Gate-emitter capacitance can also be configured for compatibility with different IGBTs.

6.1 Turn-on and Turn-off Resistors

The turn-on resistance $R_{G(on)}$ is selectable in the range 0.47Ω to 27.0Ω (63 values).

The turn-off resistance $R_{G(off)}$ is selectable in the range 1.02Ω to 56.0Ω (63 values).

The soft-turn-off resistance $R_{G(soft)}$ is selectable (63 values as for $R_{G(off)}$), but is usually restricted to the range 9.88Ω to 56.0Ω .

These values are selected by setting the following parameters:

Gate Turn On Resistor
 Gate Turn Off Resistor
 Gate Soft Turn Off Resistor

During testing it is advisable to check power dissipation in these gate resistors which will depend upon the value set, the IGBT, and the switching frequency. A thermal camera can be used to check for hot spots. If the temperature of any gate resistor appears abnormally high then refer to Amantys for advice. It is possible that by choosing a different combination of resistors the hot spot can be eliminated.

Note: For some specific customers and alternative set of resistors have been fitted to the gate drive or core. In that case, the real values of the resistors will be displayed in the Configurator.

6.2 Auxiliary Gate Capacitor

The auxiliary gate capacitance $C_{GE(aux)}$ is selectable from 0nF to 328nF (16 values). The value is selected by setting the following parameter:

Gate-Emitter Capacitance

Adding gate-emitter capacitance allows lower values of gate resistance to be used. This reduces switching time and controls di/dt , without significantly impacting dv/dt , therefore keeping switching losses down. Experimentation is required to find an optimal value. IGBT manufacturers sometimes recommend suitable values to get an acceptable trade-off between switching time, switching behaviour and low losses.

6.3 DC Link Measurement and High V_{CE} Gate Turn-off Resistor

This feature is available on the Core Gate Drive. There is a V_{CE} comparator (#4) that is used to select an alternative turn-off resistor for situations where the DC link is above a specific threshold. To avoid stress to the transient voltage suppressors (also known as TVS or transorbs) in the clamping circuit, it is desirable to slow down switching when the DC link is higher than usual for extended periods of time. For a full description of over-voltage clamping refer to 7.4.

Figure 9 shows the effect of increasing the turn-off resistor when the DC link is above a certain threshold, e.g. 2600V for a 3300V IGBT module.

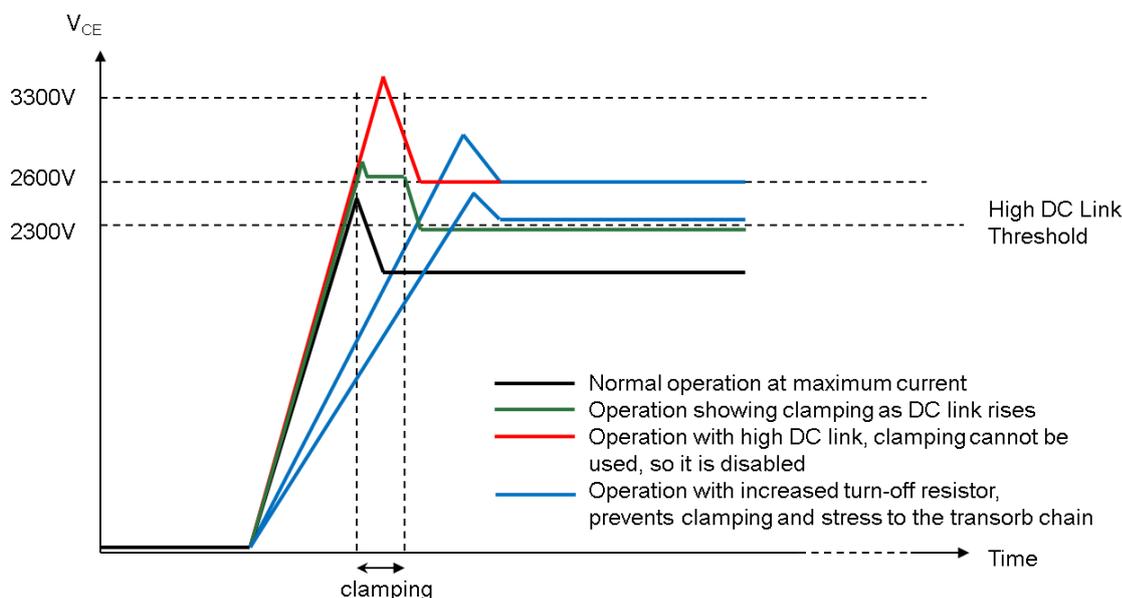


Figure 9. Effect of DC Link Measurement on turn-off switching waveform

To enable the feature, set the following parameters:

```
DC Link Measurement Enable
Vce Monitor 4 Comparator Threshold
High Vce Gate Turn Off Resistor
```

DC Link Measurement Enable is a single bit and the Vce Monitor 4 Comparator Threshold sets the high DC link threshold.

Note: This feature is also available for the On-module 3300V Gate Drive programmed with CPLD configuration SW000071, however the default configuration is SW000066 which does not have this feature. The on-module 1700V gate drive does not have this feature.

6.4 Gate Voltage Monitoring

It is possible to set voltage thresholds for the gate when on and off that generate a fault if not exceeded. The time at which the voltage is measured from the switching edge is also configurable. If the gate voltage does not exceed the threshold voltage, by the programmed time, the gate drive will generate a fault and turn-off. These measurements can be enabled or disabled using the following parameters:

```
Gate Monitor 1 Enable
Gate Monitor 2 Enable
Gate Monitor Time 1 (ON)
Gate Monitor Time 2 (OFF)
Gate Monitor 1 Comparator Threshold
Gate Monitor 2 Comparator Threshold
```

The Gate Monitor Enable parameters are single bits.

The diagram below, Figure 10, illustrates typical settings.

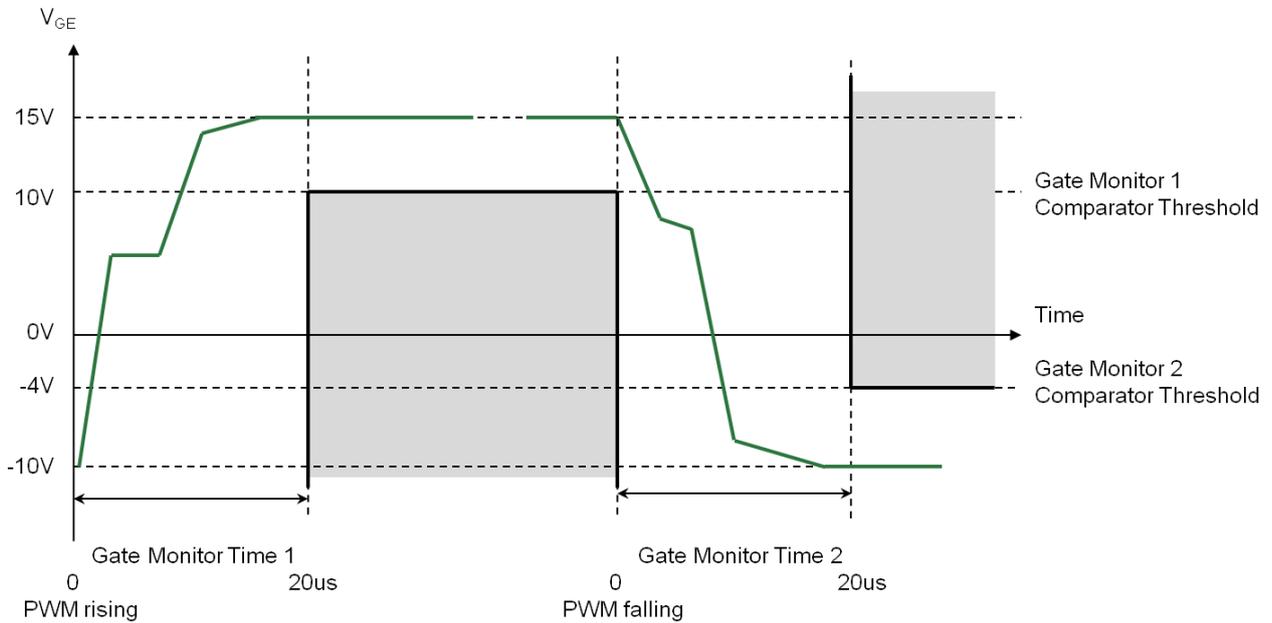


Figure 10. Gate Voltage Monitoring with turn-on threshold at 10V and turn-off threshold at -4V, both at 20us

6.5 Turn-on and Turn-off delays

It is possible to delay turn-on and turn-off to match the timing of other gate drives, or in the case of turn-on to add dead time. There are two parameters that control this behaviour which can be set in the range of 0 to 5µs as follows:

Turn On Delay
Turn Off Delay

6.6 High Frequency Limiter

It is possible to limit the maximum frequency of operation to 4.4kHz for compatibility with existing converter controllers, and still allow double pulse testing with narrow pulses through the use of a frequency limiter. The limiter is enabled by setting the following parameter:

High Frequency Limit Enable

If this bit is not set then there is no restriction on the maximum frequency. However, at some point (depending upon the gate charge of the connected IGBT) the total power consumption will exceed the maximum available and the power supply will signal an under-voltage fault.

6.7 Short Pulse Detection (AD00XA8 only)

Some free-wheeling diodes can be damaged if their turn-on time is too short (please refer to the module manufacturer for guidance). In this case, it might be desirable to generate a fault if the IGBT off-time, corresponding to diode-on time, is below a certain value.

To enable this protection, two parameters are defined:

Minimum Off-Pulse Width Minimum Off-Pulse Detect Enable
--

The pulse width can be from 0-1.3ms, although values of 20-50µs might be more appropriate. To enable the protection set the enable bit.

6.8 Variable Gate Voltage (some Cores only)

For compatibility with silicon-carbide (SiC) MOSFETs and IEGTs there is a version of the core gate drive that implements variable gate voltage. The maximum voltage swing at the gate is limited by the output MOSFETs in the drive circuit. This limit is 27V. This allows the gate voltage to be set, for example from, -5V to +22V, or -10V to +17V. The minimum gate voltage is -10V, so -15V is not possible.

To enable variable gate voltage set the following parameter:

Variable Gate Voltage Enable

If this is 0 the default is -10V to +15V. If this is set to 1, the gate voltage is set by the following parameters:

Gate Voltage when ON Gate Voltage when OFF

If a mistake is made, for example the gate voltage range is set to -10V to +20V, which is greater than the maximum swing of 27V, the gate drive may fail to power up. In this case, using a bench power supply, reduce the input voltage until the gate drive powers up correctly and reset the parameters.

Please note that for gate voltages above 15V it is necessary to ensure the power supply input to the driver core has sufficient headroom otherwise the maximum voltage will be limited by the power supply and not by the configuration parameter. This is particularly relevant if the off-module 4500V gate drive is used with another manufacturers isolating DC-DC converter.

The voltage monitors will scale appropriately with the gate voltage levels so under-voltage protection is maintained.

7 Protection Features

7.1 Gate-Emitter Clamp

The Gate-Emitter clamp connects the gate and emitter through a low impedance path when the gate drive is unpowered or if the programmable logic device is un-programmed. This holds the IGBT off and provides resilience to transients that could cause a spurious turn-on of the IGBT.

7.2 Gate Drive Supply Under-voltage Protection

Under-voltage protection of the gate drive is provided to prevent operation of the IGBT at low input voltage and protect the IGBT module from damage due to high on-state losses resulting from low gate voltage. The gate drive contains under-voltage comparators to monitor the gate drive supply rails with respect to the 3.3V supply,

- Positive gate voltage: V_{g+} , e.g. for 15.0V the threshold is set at 12.5V
- Negative gate voltage: V_{g-} , e.g. for -10.0V the threshold is set at -6.5V
- 45V supply used for the clamping circuit, the threshold is set at 30V

If any of the supplies drops below their thresholds the IGBT will be turned off and the FB/ACK output driven LOW to indicate a fault. The IGBT will remain off until the supplies are restored, the under-voltage timeout is exceeded and the PWM input is driven low to high.

The 3.3V supply is automatically monitored by the gate drive. If the supply falls below the minimum voltage threshold (2.375V) the outputs are turned off, which ensures the IGBT is held off.

There is a 75V supply on the 3300 V on-module gate drive (45V on the Core Gate Drive) for the desaturation protection circuits. Rather than monitor the supply directly, the presence or absence of current (~3mA) flowing in the desaturation diodes is monitored by the gate drive. This protects against failure in the full desaturation protection circuit rather than just the supply voltage.

7.3 IGBT Short Circuit Protection

Short circuit protection of the IGBT is achieved by monitoring the IGBT for desaturation. The collector-emitter voltage (V_{CE}) is monitored at switch-on and during the on state. If a short circuit (desaturation of the IGBT) is detected, the FB/ACK output is driven LOW to indicate a fault, and a type 1 or type 2 fault is recorded.

The conditions for the detection of the IGBT module desaturation are as follows. At switch on, V_{CE} is checked using various voltage comparators. If the V_{CE} voltage has not fallen below the monitored voltage in a specific time window then it is assumed that a short circuit or over-current event has occurred. If that event occurs within the first 10 μ s a type 1 event is recorded, and after that time a type 2 event is recorded.

A more thorough description of the desaturation protection and configuration registers can be found in Section 8.

On detecting a desaturation event the IGBT is turned off automatically by the gate driver and a fault signal indicated on the FB/ACK output. It is possible to prevent the gate drive turning off the IGBT (for use in 3-level converters) by setting the disable turn-off on fault configuration parameter:

Disable Turn-off on Fault

For the on-module 1700V Gate Drive this parameter is called converter level and should be set as 2 (2-level) or 3 (3-level):

Converter Level

Both parameters achieve the same thing.

If disable turn-off on fault is enabled, or the converter level is set to 3 then the FB/ACK output immediately goes low (light off) to indicate a fault, and the converter controller must be designed to ensure that all IGBTs are turned off in the correct sequence before 10 μ s is exceeded.

After a fault has been detected, the IGBT gate will be held low (at -9V for the on-module gate drive and -10V for the Core Gate Drive) and switching will be inhibited for the duration programmed into the following parameter:

Fault Lockout Time

This is to allow the IGBT chip temperature to stabilise and protect the IGBT.

7.4 Over-voltage Two-level Clamping

At turn-off, when the IGBT is switching, the di/dt (the rate of change of collector current with respect to time) through the stray inductances in the power circuit may cause a transient voltage overshoot across the IGBT collector-emitter terminals. The overshoot can cause damage to the IGBT if it exceeds the IGBT maximum collector to emitter voltage rating, $V_{CE(max)}$. V_{CE} overshoots at turn off may be limited by the V_{CE} clamp. A discussion about clamping can be found in [3].

The clamp is implemented with a series string of transient voltage suppressors (also known as TVS diodes or transorbs) connected between the collector and the gate. As the collector voltage rises, the TVS chain conducts and current flows into the gate of the IGBT, effectively slowing down the turn-off. There is a switch that opens and disconnects the TVS chain 5 μ s after turn-off, which increases the clamping voltage until the next turn-off signal is received. This is called two-level clamping, and allows a higher DC link voltage to be used, whilst still clamping the turn-off overshoot.

A TVS is not a perfect component. It conducts over a range of voltage with conduction current increasing with voltage above the threshold. It also has a wide tolerance and temperature dependence. For this reason it is necessary to set the clamping level quite low compared to the maximum blocking voltage of the IGBT, for example 2300-2600V for a 3300V IGBT. Without two-level clamping the TVS would start to conduct as the DC link rises above the TVS threshold and the IGBT would be turned-on inadvertently. The diagram below, Figure 11, shows the effect.

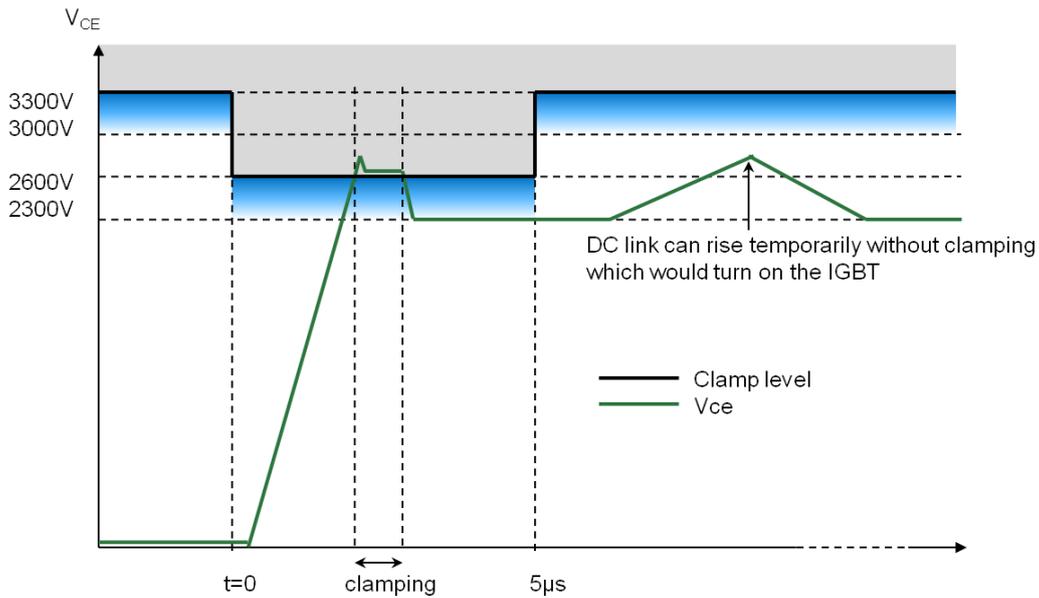


Figure 11. Over-voltage Two-level Clamping

The TVS components that implement the voltage clamping are mounted on the on-module gate drive, the distribution board or module interface card, the latter providing flexibility for use with different IGBT voltage ranges. Two-level clamping is turned on by default, but may be disabled by setting the Clamp Disable configuration bit to 1.

`Clamp disable`

As mentioned earlier V_{CE} clamping works by temporarily increasing V_{GE} in order to soften the IGBT turn-off, keeping the IGBT in its active region for longer in order to control the di/dt slope and limit the overshoot voltage. When the energy in the stray inductance dissipates, the overshoot voltage decays and the IGBT turns off normally. This can be seen in Figure 12.

Note: The AD00XA8 gate drive has a simplified module interface card for compatibility with existing solutions in the market. In this case clamping is single level (set at the 2300-2600V level) for a 3300V IGBT and the clamp cannot be disabled. The clamp cannot be disabled on the on-module 1700V Gate Drive which has a reduced number of configuration parameters.

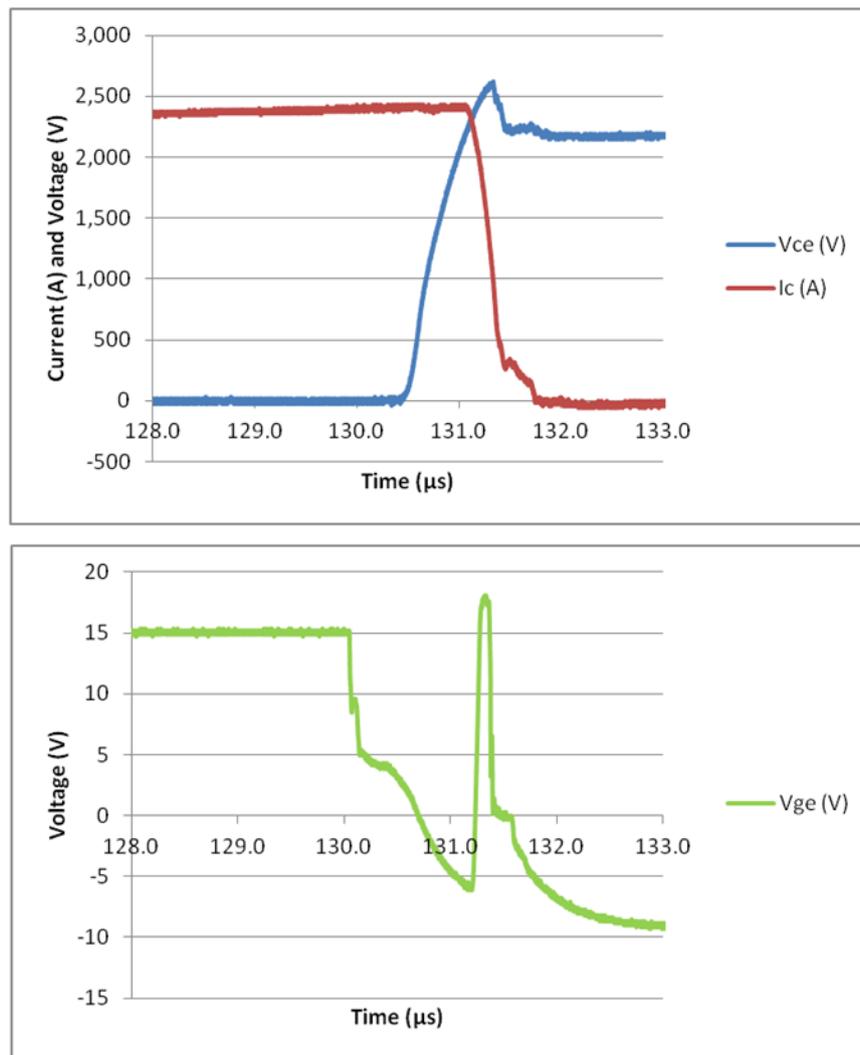


Figure 12. Over-voltage Clamping, showing gate voltage rise to slow down turn-off

8 Collector Voltage Monitoring and Desaturation Protection

This section describes the desaturation protection for the majority of Amantys gate drives. However, the on-module 1700V gate drive has a simplified mechanism with a fixed desaturation voltage level of 65V and a programmable desaturation time.

Desaturation Detection Time 1
Desaturation Detection Time 2

Desaturation detection time 1 is the time at which a comparator begins to monitor the $V_{CE(on)}$ voltage, typically 7.5 μ s after the gate voltage goes high. Desaturation detection time 2 is simply used by the fault monitoring software to determine whether the fault is a type 1 or type 2 short circuit. Typically, this is set at 10 μ s.

The on-module 1700V gate drive detects the V_{ce} voltage using a potential divider. Other Amantys gate drive have both a potential divider and a current source with a chain of diodes for high voltage protection. In general the current source is a more robust method of detecting short circuits because potential dividers implemented with very high value resistors (M Ω), to limit power dissipation, can easily pick up interference.

The following sections describe the V_{ce} monitors and diode desaturation protection. In general, the diode desaturation protection is preferred and the V_{ce} monitors are only used for very slow switching IGBTs (such as older 4500V and 6500V single switch modules).

8.1 V_{CE} monitors

There are three voltage comparators, used to measure V_{CE} . These comparators are used to measure voltages above the desat diode chain maximum threshold of 57V (or 36V on the Core Gate Drive). The voltage is set by configuring the following parameters:

Vce Monitor 1 Comparator Threshold
Vce Monitor 2 Comparator Threshold
Vce Monitor 3 Comparator Threshold

These can be enabled to operate in any of four time windows, as described below, using the following parameters:

Vce Monitor 1 Enable
Vce Monitor 2 Enable
Vce Monitor 3 Enable

Important: Each of these parameters is 4-bits wide (values 0-15) where bit 0 enables a monitor in time window 0, bit 1 enables a monitor in time window 1, and so on.

8.2 Desat diode chain

The desat diode chain enables a threshold to be set for detection of $V_{CE(on)}$ from 0 to 57V (for the on-module 3300V gate drive) or 0 to 36V (for the Core Gate Drive).

Desat Diode Comparator Threshold

This can be enabled to operate in any one of four time windows, as described below, using the following parameter:

Desat Enable

Important: This parameter is 4-bits wide where bit 0 corresponds to time window 0, bit 1 to time window 1 and so on.

Note: The AD00XA8 gate drive has two desat diode comparator thresholds and two enable bits.

8.3 Configuring the desaturation protection

Four time parameters are provided to configure four time windows. They are:

```
Desat Window Time 1
Desat Window Time 2
Desat Window Time 3
Desat Window Time 4
```

Each time is measured from the incoming PWM signal and is a value from 0 to 50µs. The physical timers can be programmed up to 1.31ms, but values above 50µs are not recommended as a fault may be generated. Time parameters can have the same value, but should adhere to the following relationship to correctly define the windows,

$$\text{Time 1} \leq \text{Time 2} \leq \text{Time 3} \leq \text{Time 4}$$

Figure 13, shows the relationship between time parameters, time windows and enable signals.

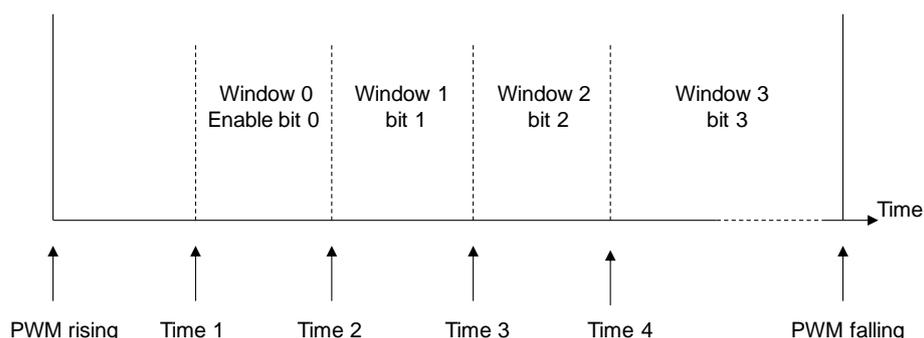


Figure 13. Relationship between Time Parameters, Windows and Enable bits

As an example for a 6500V IGBT, where V_{CE} falls slowly after turn-on, four windows and four voltage levels might be defined, as shown in the diagram below, Figure 14.

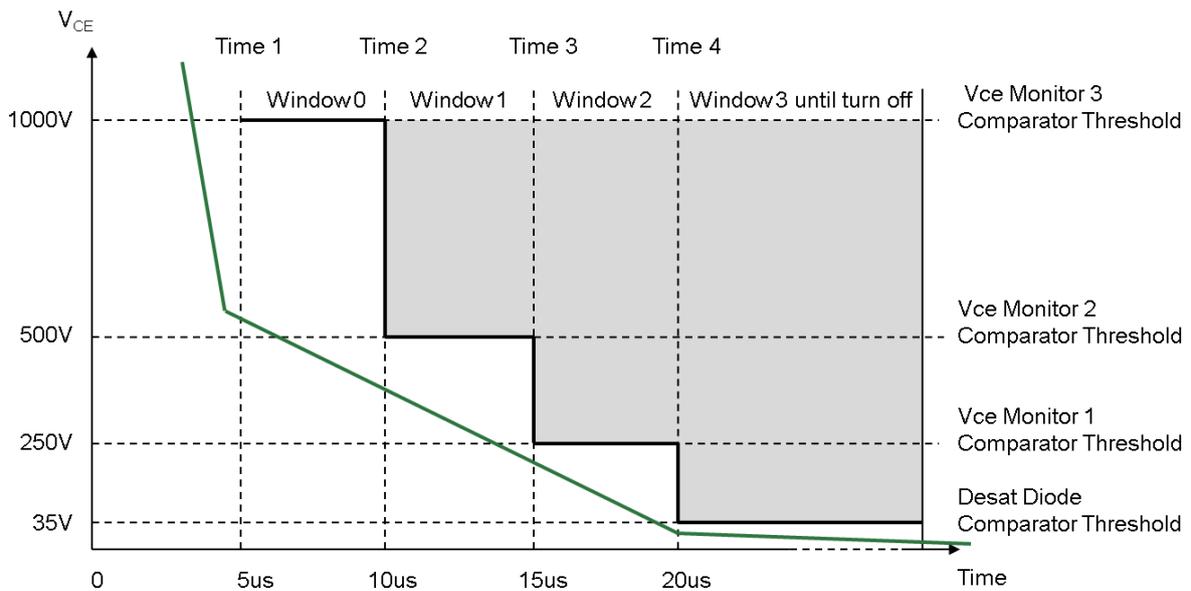


Figure 14. Desaturation Protection Example for 6500V IGBT; the green line is the collector voltage

The following tables describe the configuration parameter settings.

Parameter	Window				Value
	3	2	1	0	
Desat Enable	1	0	0	0	8
Vce Monitor 1 Enable	x	1	0	0	4
Vce Monitor 2 Enable	x	x	1	0	2
Vce Monitor 3 Enable	x	x	x	1	1

Note: the bit order is reversed from what might be expected looking at the diagram, but defined this way so that it is easy to see the relationship between the bit position and the value programmed into the register.

x = don't care

Parameter	Value
Desat Diode Comparator Threshold	35V
Vce Monitor 1 Comparator Threshold	250V
Vce Monitor 2 Comparator Threshold	500V
Vce Monitor 3 Comparator Threshold	1000V

Desat Window Time 1	5µs
Desat Window Time 2	10µs
Desat Window Time 3	15µs
Desat Window Time 4	20µs

Table 3. Example 6500V Parameters

Figure 15 is an example for a 3300V IGBT with just two windows and two voltage levels.

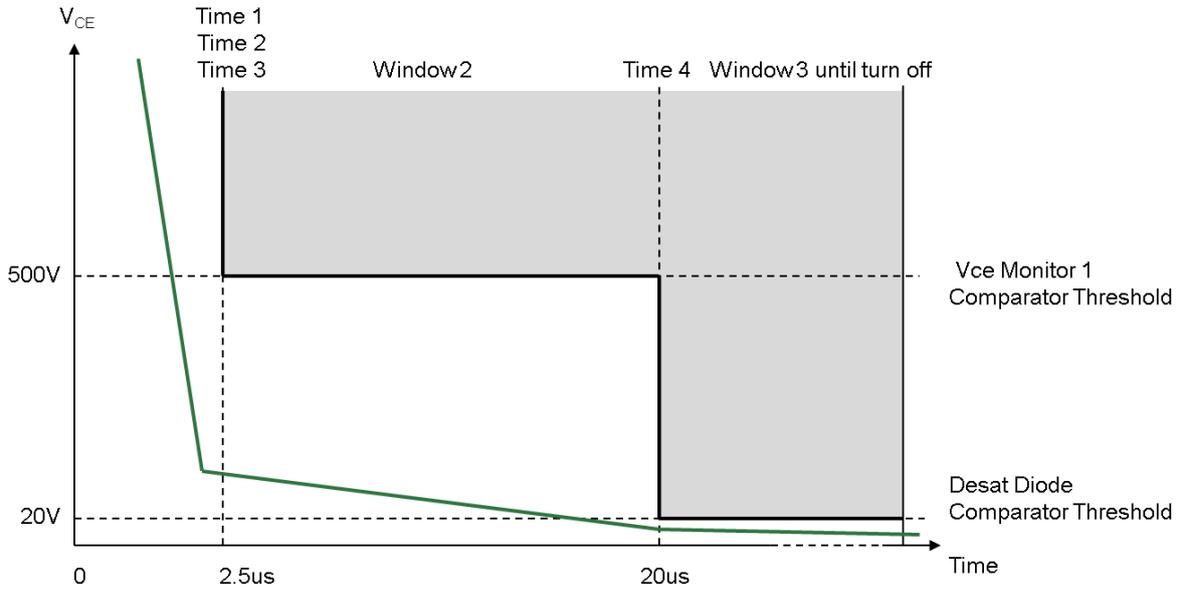


Figure 15. Desaturation Protection Example for 3300V IGBT; the green line is the collector voltage

The following tables describe the configuration parameter settings.

Parameter	Window				Value
	3	2	1	0	
Desat Enable	1	0	0	0	8
Vce Monitor 1 Enable	x	1	0	0	4
Vce Monitor 2 Enable	0	0	0	0	0
Vce Monitor 3 Enable	0	0	0	0	0

Note: the bit order is reversed from what might be expected looking at the diagram, but defined this way so that it is easy to see the relationship between the bit position and the value programmed into the register.

x = don't care

Parameter	Value
Desat Diode Comparator Threshold	20V
Vce Monitor 1 Comparator Threshold	500V
Vce Monitor 2 Comparator Threshold	-
Vce Monitor 3 Comparator Threshold	-

Desat Window Time 1	2.5µs
Desat Window Time 2	2.5µs
Desat Window Time 3	2.5µs
Desat Window Time 4	20µs

Table 4. Example 3300V Parameters

Note that in this example the Desat Diode Comparator Threshold is low at 20V. This can be used as an over-current detector; however testing will be required to set Time 4 and an appropriate Vce Monitor 1 Comparator Threshold so that the IGBT will be turned off in the case of a short circuit during the period up to Time 4. If the Desat Diode Comparator Threshold were set higher, at 35V (or 50V on the 3300V Gate Drive) for example, then it is possible that the V_{CE} Monitors would not be required for 1200V, 1700V and 3300V IGBTs.

Note that AD00XA8 has two desat diode comparators, so one can be set at 35V and the other can be used as an over-current monitor at a lower voltage.

8.4 V_{CE} Monitor and Desat Diode Filter

The various V_{CE} Monitor signals and the Desat Diode signal are combined with their respective enable bits and ORed together to form a single fault signal as shown in Figure 16.

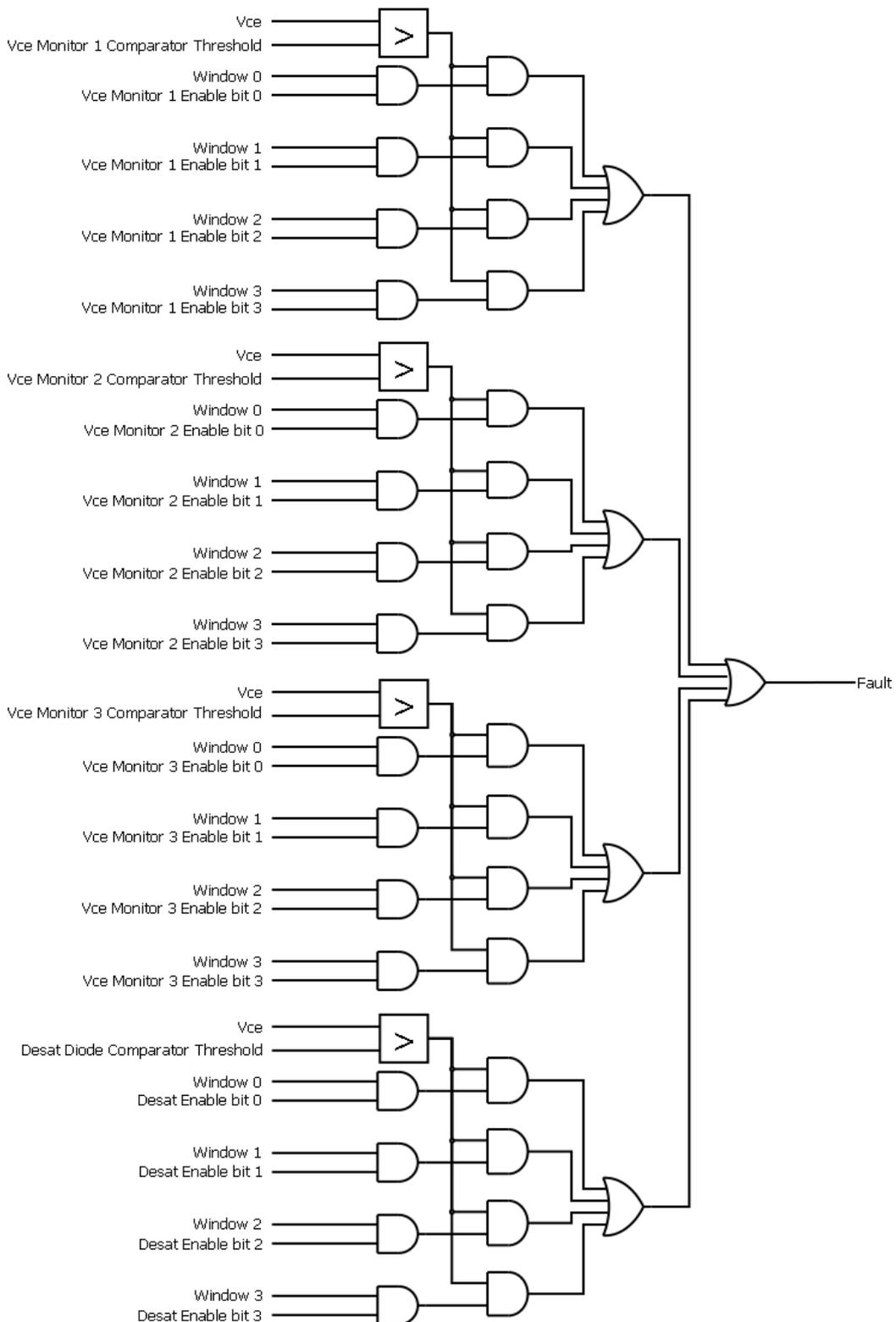


Figure 16. Fault Logic. Note: AD00XA8 has two Desat Diode Comparators

This is passed through a noise rejection filter with a time constant defined as follows. If the fault signal is high (logic '1') for more than the specified time constant then the gate drive will signal a

fault. The time constant for the filter can be configured in the range 0 to 5 μ s by setting the following parameter:

Vce Monitor Filter Time Constant

Note: For detection of short circuit type 1 (see 8.5), it is recommended that the sum of the filter time constant and the start of Time Window 1 should be less than or equal to 7.5 μ s. This means that in the event of a short, the fault signal will be asserted at 7.5 μ s after turn on, and with sufficient time to turn-off the IGBT within its 10 μ s rating (provided that the soft turn-off resistor $R_{G(\text{soft})}$ is sufficiently low to turn off the IGBT within 2.5 μ s).

8.5 Type 1 and Type 2 short circuits

There are different definitions of type 1 and type 2 short circuits. Amantys defines a type 1 as a desaturation event within the first 10 μ s after the receipt of the incoming PWM turn-on command. Type 2 is any desaturation or over-current event after the initial 10 μ s. For a description of short circuit types refer to [4].

Typically type 1 short circuits occur when a device is switched on into a short, i.e. in the case of a shoot-through due to failure of the opposing IGBT in a phase leg or a direct short imposed from collector to emitter. Typical waveforms are shown in Figure 17.

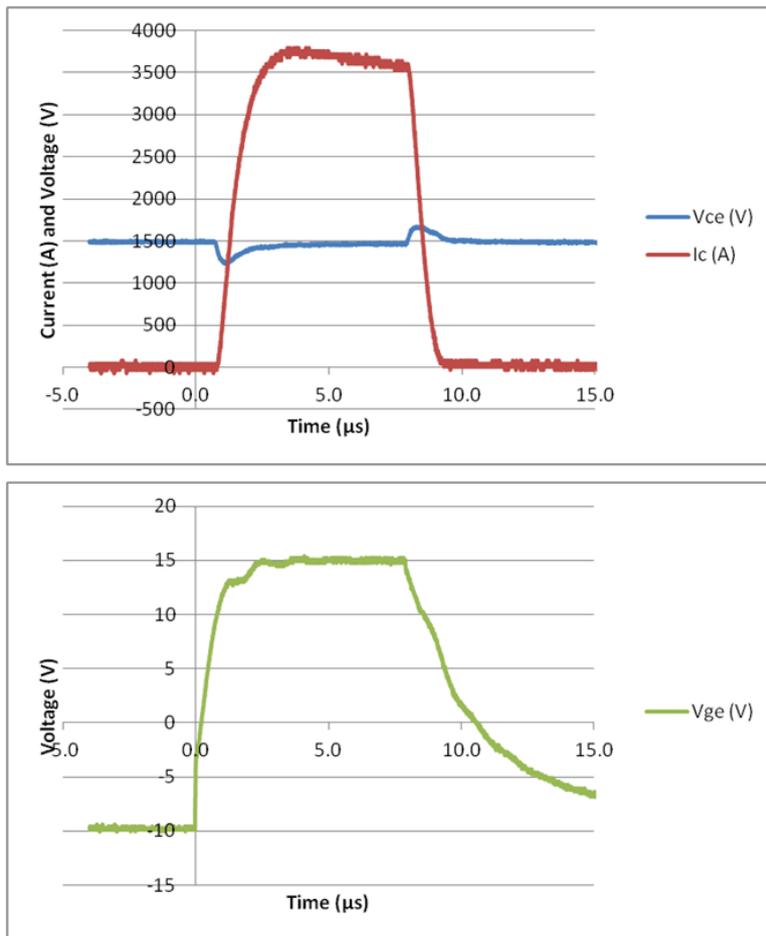


Figure 17. Short Circuit Type 1 showing turn-off before 10 μ s

Type 2 events generally occur due to a short in the load and are characterised by higher inductance and therefore slower current rise times. Typical waveforms are shown in Figure 18.

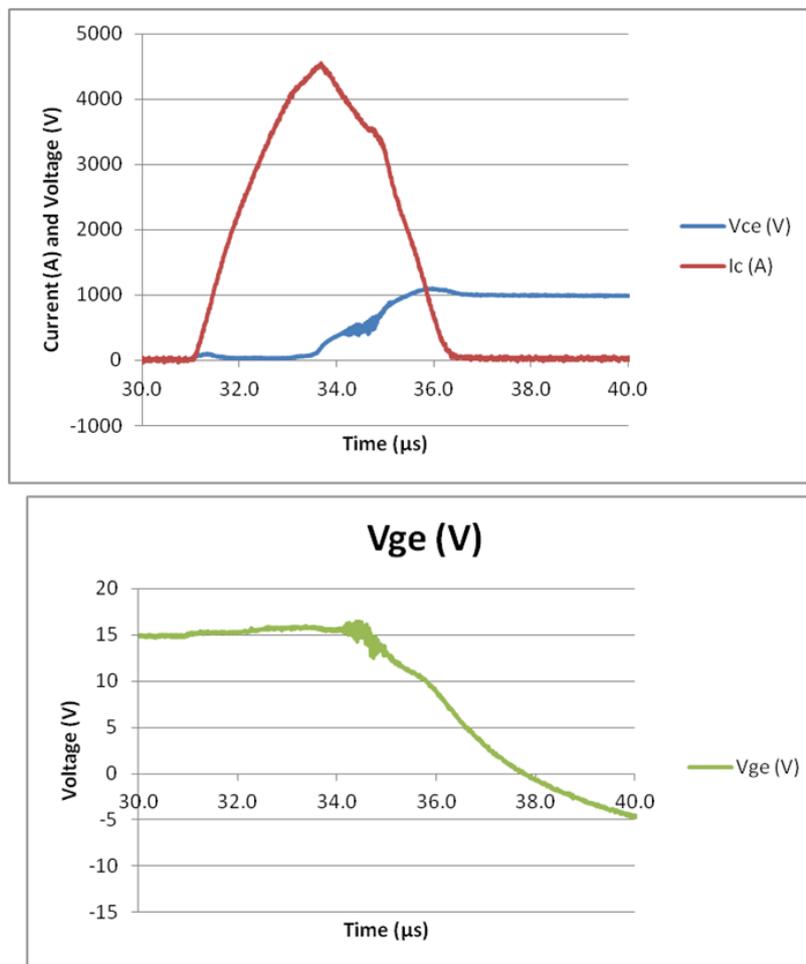


Figure 18. Short Circuit Type 2 detection and turn-off

Some IGBT manufacturers recommend that in the case of a type 2 short-circuit the current is allowed to stabilise before turning off. The following parameter allows this time to be set:

Type 2 Short Circuit to Turn Off Delay

This is a pure delay, which waits for a specific time from the fault signal going high before turning off the IGBT.

Note: It is unnecessary to set both a turn-off delay and a long Vce Filter Time Constant, see 8.4. So for example if the filter time constant is set at 3µs, then the IGBT will not be turned off until 3µs after the event is detected. It is recommended that the filter is used rather than this delay, unless there is a reason that a long filter time constant is not appropriate.

8.6 Inductive Type 2 short circuits

If the inductance to the short is large, then the di/dt during the short will be lower than usual. It is possible that the IGBT will be ON with higher than normal current for a long time. As the current is rising slowly, the IGBT may overheat before the device desaturates.

For this reason it is possible to set the Desat Diode Threshold low, typically at least the value of $V_{CE(on)}$ for twice rated current. Due to the existence of the high voltage blocking diodes in the diode desat detection circuit, it is necessary to add ~6V to the V_{CE} threshold read from the datasheet. Note also that this is temperature dependent, so a value in the range 15-20V may be sensible, but avoid values below 10V. To avoid false tripping please refer to Amantys for guidance.

Due to device margins there will always be a grey area between the maximum normal operating current, and the point at which desaturation or over-current is detected. Even with a circuit that measures di/dt it is difficult to set a comparator that can distinguish between normal and abnormal di/dt .

Amantys recommends that over-current detection is configured with knowledge of the application, circuit characteristics and possible fault scenarios.

9 di/dt Protection (AD00XA8 only)

Most Amantys gate drives do not implement di/dt protection for the following reasons.

To detect di/dt there needs to be a connection to the power-emitter of the IGBT module, which can be inconvenient. The voltage measured across the inductance between the auxiliary-emitter and the power-emitter is used to indicate the di/dt.

$$V = -L_s \cdot di/dt$$

Where L_s is the emitter stray inductance which is typically in the range of 5-10nH. If, for example, the di/dt to be detected is 2kA/ μ s and the inductance is 10nH then the voltage generated will be 20V. This is quite a low voltage level compared to the desaturation detection voltage which rises to 100's of volts very rapidly. For desaturation protection the diode desaturation protection mechanism is advised instead of di/dt protection.

Because there is a loop of wire between the auxiliary emitter and the power emitter this is also susceptible to pick-up inductively coupled noise. So, to use di/dt detection careful routing of cables is essential, and the system needs to be carefully configured to avoid false trips.

For compatibility with existing gate drives in the market, the AD00XA8 has a dedicated power-emitter cable connection and does implement di/dt protection.

There are two configuration parameters defined to set two possible voltages:

```
di/dt Monitor 1 Threshold
di/dt Monitor 2 Threshold
```

The threshold is a value from 0-255. Values less than 128 are negative voltages, corresponding to positive di/dt, and values above 128 are positive voltages corresponding to negative di/dt. Some experimentation is required to set up the levels. In general, the objective is to detect high di/dt that exists for a certain amount of time. To avoid tripping during a normal turn-on event there are two di/dt filters defined. Turn-on typically lasts for 500-2000ns, so it is advisable to set the di/dt filter time constant to a value greater than 2 μ s. Separate filters can be set of each of the thresholds.

```
di/dt Filter 1 Time Constant
di/dt Filter 2 Time Constant
```

To enable the protection there are two bits defined, one for each of the thresholds and filters.

```
di/dt Enable 1
di/dt Enable 2
```

The scaling of voltage levels to the 3V3 comparators used on the gate drive are set by resistors. These resistors can be modified for different scale factors but by default they are set so that the following mapping exists between the threshold value and the voltage detected.

If the di/dt Monitor Threshold = 0 this corresponds to a voltage of -15V. Therefore, if $L_s = 10\text{nH}$, then,

$$di/dt = -(-15\text{V} / 10\text{nH}) = 1.5\text{kA}/\mu\text{s}$$

If the di/dt Monitor Threshold = 255 this corresponds to a voltage of +15V. Therefore, if $L_s = 10\text{nH}$, then,

$$di/dt = -(15\text{V} / 10\text{nH}) = -1.5\text{kA}/\mu\text{s}$$

So the range is -15V to +15V with approximately 0.118V per bit.

To set up the di/dt protection use the following steps.

1. Decide which level of di/dt is a fault and calculate the di/dt Monitor Threshold 1.
2. Decide for how long that level must be present for a fault to be indicated, and set the di/dt Filter 1 Time Constant.
3. Set di/dt Enable 1.
4. If more than one level and duration is required, repeat the process for monitor 2.

With this scheme positive and negative di/dt can be detected which may be useful in some circumstances.

If di/dt protection is not required, or there is no power emitter cable, leave the enable bits set to 0.

10 Power Insight Communication

Power Insight is a data communications mechanism that operates by superimposing a data signal onto the PWM and FB/ACK signals. It enables bi-directional communication between a converter controller and a gate drive using the existing fibre-optic interface. Power Insight defines two methods of sending data over the fibre-optic link: Compatibility Mode and Normal Mode. Compatibility Mode is so called because it is compatible with Power Integrations (CT-Concept) signalling.

10.1 Compatibility Mode

In Compatibility Mode the width of the acknowledge pulse is modulated to signal either a data '0' or '1'. This is uni-directional data transmission from gate drive to converter controller and is the default when the gate drive is turned on. The Power Insight adapter can be used to monitor the data, which comprises measurements and information about the gate drive. Because this is uni-directional it is not possible to change the data or send configuration information to the gate drive. For bi-directional communication the gate drive is switched into Normal Mode.

10.2 Normal Mode

A gate drive will switch from Compatibility Mode to Normal Mode whenever a data packet is sent which conforms to the Normal Mode protocol.

In Normal mode, pulses are modulated on to the fibre using a pulse-position modulation scheme to signal either a data '0' or '1'. This allows a much greater data rate (approximately 500kbits/s) compared to Compatibility Mode, and enables bi-directional communication.

When in Normal Mode a delay of 450-500ns is added to the PWM signal as it is received at the gate drive so that the data can be decoded from the PWM signal. The FB/ACK also incurs a similar delay as the data is encoded onto the line. A full system implementing bi-directional data communication will incur a total delay of <1us in each direction. For more information and assistance with Power Insight protocol, please contact Amantys.

10.3 Developing a Converter Controller that uses Power Insight

Amantys has developed the Power Insight Adapter and Power Insight Configurator to allow users to configure and monitor gate drives in the field during development and commissioning. To make use of the Power Insight features in a running converter it is necessary to develop a converter controller that is compatible with the Power Insight protocol. Typically this would involve integration of programmable logic for the physical interface and a processor to run the higher levels of messaging protocol. As every manufacturers' converter is different, the solution must be developed in conjunction with Amantys, so a discussion is recommended and it is worth considering the following questions,

- What measurements are required by the converter controller?
- How regularly are the measurements required, once an AC cycle or once a switching cycle?
- Are the measurements part of the converter's control or protection scheme?
- What is the interface between the converter controller and the Power Insight encoder/decoder?
- Is communication bi-directional, i.e. does the gate drive need to be updated regularly?

11 Measurement of Voltage, Current and Temperature

11.1 Analog-to-Digital Converters (ADC)

The microcontroller on the gate drive has an analog-to-digital converter (ADC) peripheral with multiple input channels. This is used to measure the following:

- Gate voltage at turn-on and turn-off
- Collector voltage at turn-on and turn-off
- Gate Drive ambient temperature
- NTC temperature sensor (if one exists)
- Current and di/dt (not enabled by default: please contact Amantys if you wish to use these)

Timing of the measurements relative to the turn-on and turn-off command are programmable. The gate drive also employs a filter to some signals. A full description of the measurement capability is outside the scope of this document, so refer to Amantys for further information.

11.2 Event Counters

The gate drive contains a number of counters for counting events that have occurred since manufacture and since the last time the counter was reset. These are:

- Short Circuit Type 1 events
- Short Circuit Type 2 events
- Clamp events
- Power Supply Under Voltage

By comparing the event counters on one gate drive with those on another in the same or similar stack, abnormal behaviour of a gate drive, IGBT or converter controller can be detected.

Note that in some cases a normal power-off event may be recorded as a power supply under-voltage as there is no way for the gate drive to detect the difference between a slow falling supply and a temporary under-voltage. Filtering has been applied to avoid recording multiple under-voltage events in quick succession; however this value is most useful when compared to the reading from other gate drives in the same converter.

11.3 On-board Temperature Sensor

A discrete temperature sensor or a temperature sensor in the micro-controller measures the gate drive temperature (T_{GD}) and reports it by Power Insight in degrees Celsius. Due to local heating this reads approximately 15°C above ambient. As this is not an accurate measurement, it is best used relative to other gate drives in the converter as an indicator of abnormal conditions.

11.4 IGBT Module Temperature Sensor

If the IGBT module has an NTC thermistor it will be connected to one of the analog channels and reported via Power Insight, either as a temperature or a resistance measurement.

12 References

[1] Broadcom data sheets [AFBR-15x9Z DC to 10 Mbd Versatile Link Fiber Optic Analog Transmitter for 1 mm POF and 200 µm PCS](#) and [AFBR-16xxZ and AFBR-26x4Z/25x9Z DC-50MBd Versatile Link Fibre Optic Transmitter and Receiver for 1 mm POF and 200 µm PCS](#).

[2] Firecomms data sheets [FR50MxxR Datasheet RevD.pdf](#) and [FT10MHLR Datasheet RevE.pdf](#).

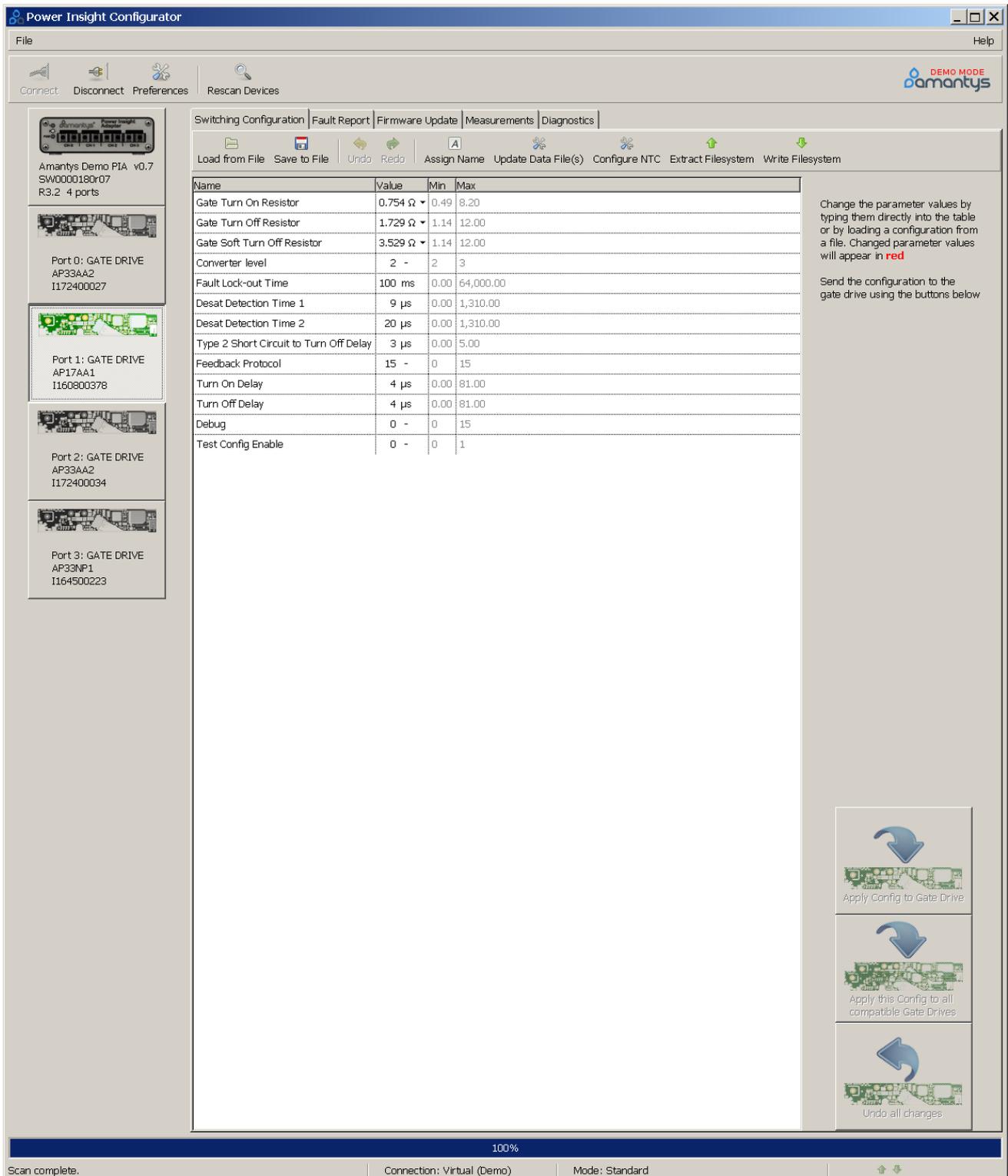
[3] See [littelfuse tvs diode protection for vfds igbt inverters.pdf](#) for a discussion about over-voltage clamping.

[4] See [igbt-overcurrent-and-short-circuit-protection-in-industrial-motor-drives.html](#), for a discussion about short circuit types.

Revision Table

Revision	Comments	Date
03	First external release	20-Jun-2017
04	Including multiple improvements, new figures and waveforms	21-Aug-2017
05	Minor errata and reformatting of configurable parameters	01-Sep-2017
06	Changed parameter t1 on p12, was 50ns now 500ns or 1us (#1647)	03-Nov-2017
07	Updated to include AD and AV series boards and add additional information about new configuration options	20-Dec-2019
08	Updated desaturation protection examples	13-Jan-2020

Appendix 1: AP12A/AP17A On-module Gate Drive (CPLD part number SW000035)



Power Insight Configurator

File | Help

Connect | Disconnect | Preferences | Rescan Devices

Amantys Demo PIA v0.7
SW0000180r07
R3.2 4 ports

Port 0: GATE DRIVE
AP33AA2
I172400027

Port 1: GATE DRIVE
AP17AA1
I160800378

Port 2: GATE DRIVE
AP33AA2
I172400034

Port 3: GATE DRIVE
AP33NP1
I164500223

Switching Configuration | Fault Report | Firmware Update | Measurements | Diagnostics

Load from File | Save to File | Undo | Redo | Assign Name | Update Data File(s) | Configure NTC | Extract Filesystem | Write Filesystem

Name	Value	Min	Max
Gate Turn On Resistor	0.754 Ω	0.49	8.20
Gate Turn Off Resistor	1.729 Ω	1.14	12.00
Gate Soft Turn Off Resistor	3.529 Ω	1.14	12.00
Converter level	2 -	2	3
Fault Lock-out Time	100 ms	0.00	64,000.00
Desat Detection Time 1	9 μ s	0.00	1,310.00
Desat Detection Time 2	20 μ s	0.00	1,310.00
Type 2 Short Circuit to Turn Off Delay	3 μ s	0.00	5.00
Feedback Protocol	15 -	0	15
Turn On Delay	4 μ s	0.00	81.00
Turn Off Delay	4 μ s	0.00	81.00
Debug	0 -	0	15
Test Config Enable	0 -	0	1

Change the parameter values by typing them directly into the table or by loading a configuration from a file. Changed parameter values will appear in **red**.

Send the configuration to the gate drive using the buttons below

Apply Config to Gate Drive

Apply this Config to all compatible Gate Drives

Undo all changes

100%

Scan complete. | Connection: Virtual (Demo) | Mode: Standard

Appendix 2: AP12G/AP17G/AP33A On-module Gate Drive (CPLD part number SW000066)

Power Insight Configurator

File Help

Connect Disconnect Preferences

AMANTYS PIA v0.9
SW000018r12
R3.9rc2 4 ports

Port 3: GATE DRIVE
PROD_CODE
No serial number

Switching Configuration | Fault Report | Firmware Update | Measurements | Diagnostics

Load from File Save to File Undo Redo Assign Name Update Data File(s) Configure NTC Extract Filesystem Write Filesystem

Name	Value	Min	Max
Gate Turn On Resistor	1.049 Ω	0.47	27.00
Gate Turn Off Resistor	5.974 Ω	1.02	56.00
Gate Soft Turn Off Resistor	22.000 Ω	1.02	56.00
Gate-Emitter Capacitance	0.000 nF	0.00	328.00
Disable Turn-off on Fault	0	0	1
Feedback Protocol	0	0	15
Fault Lock-out Time	100 ms	0.00	64,000.00
Desat Window Time 1	2.5 μ s	0.00	1,310.00
Desat Window Time 2	2.5 μ s	0.00	1,310.00
Desat Window Time 3	2.5 μ s	0.00	1,310.00
Desat Window Time 4	20 μ s	0.00	1,310.00
Gate Monitor 1 Time (ON)	20 μ s	0.00	1,310.00
Gate Monitor 2 Time (OFF)	20 μ s	0.00	1,310.00
Turn On Delay	0 μ s	0.00	5.00
Turn Off Delay	0 μ s	0.00	5.00
Type 2 Short Circuit to Turn Off Delay	0 μ s	0.00	5.00
Vce Monitor Filter Time Constant	5 μ s	0.00	5.00
Desat Enable	12	0	15
Vce Monitor 1 Enable	0	0	15
Vce Monitor 2 Enable	0	0	15
Vce Monitor 3 Enable	0	0	15
Gate Monitor 1 Enable	1	0	1
Gate Monitor 2 Enable	0	0	1
Desat Diode Comparator Threshold	57 V	0.00	57.00
Vce Monitor 1 Comparator Threshold	494.59 V	-404.00	3,616.00
Vce Monitor 2 Comparator Threshold	3600.24 V	-404.00	3,616.00
Vce Monitor 3 Comparator Threshold	3600.24 V	-404.00	3,616.00
Gate Monitor 1 Comparator Threshold	10.06 V	-15.50	18.80
Gate Monitor 2 Comparator Threshold	-4.07 V	-15.50	18.80
Current Measurement Threshold	0 %	0.00	100.00
di/dt Measurement Threshold	0 %	0.00	100.00
Current Offset Compensation	0 %	0.00	100.00
Series Resistance Compensation	0 %	0.00	100.00
Fibre Drive Current	5.46 mA	1.82	6.37
Clamp Disable	0	0	1
High Frequency Limit Enable	0	0	1
Test Config Enable	0	0	1
Debug	0	0	15

Change the parameter values by typing them directly into the table or by loading a configuration from a file. Changed parameter values will appear in **red**

Send the configuration to the gate drive using the buttons below

Apply Config to Gate Drive

Apply this Config to all compatible Gate Drives

Undo all changes

100%

Scan complete. Connection: Console (USB FTDI:Test/1234) Mode: Standard

Appendix 3: AV17/AV33AP0xB Fixed Gate Voltage Core (CPLD part number SW000072r05)

Power Insight Configurator

File Help

Connect Disconnect Preferences Rescan Devices

DEMO MODE
Amantys

Switching Configuration | Fault Report | Firmware Update | Measurements | Diagnostics

Load from File Save to File Undo Redo Assign Name Update Data File(s) Configure NTC Extract Filesystem Write Filesystem

Name	Value	Min	Max
Gate Turn On Resistor	1.017 Ω	0.47	27.00
Gate Turn Off Resistor	2.141 Ω	1.02	56.00
Gate Soft Turn Off Resistor	12.000 Ω	1.02	56.00
DC Link Measurement Enable	0	0	1
High Vce Gate Turn Off Resistor	7.765 Ω	1.02	56.00
Gate-Emitter Capacitance	150.000 nF	10.00	328.00
Disable Turn-off on Fault	0	0	1
Feedback Protocol	0	0	15
Fault Lock-out Time	100 ms	0.00	64,000.00
Desat Window Time 1	7.5 μ s	0.00	1,310.00
Desat Window Time 2	20 μ s	0.00	1,310.00
Desat Window Time 3	0 μ s	0.00	1,310.00
Desat Window Time 4	400 μ s	0.00	1,310.00
Gate Monitor 1 Time (ON)	5 μ s	0.00	1,310.00
Gate Monitor 2 Time (OFF)	5 μ s	0.00	1,310.00
Turn On Delay	0 μ s	0.00	5.00
Turn Off Delay	0 μ s	0.00	5.00
Type 2 Short Circuit to Turn Off Delay	3 μ s	0.00	5.00
Vce Monitor Filter Time Constant	0.3 μ s	0.00	5.00
Desat Diode 1 Enable	0	0	15
Vce Monitor 1 Enable	0	0	15
Vce Monitor 2 Enable	0	0	15
Vce Monitor 3 Enable	0	0	15
Gate Monitor 1 Enable	1	0	1
Gate Monitor 2 Enable	0	0	1
Desat Diode 1 Comparator Threshold	0 V	0.00	35.29
Vce Monitor 1 Comparator Threshold	2496.71 V	-404.00	3,616.00
Vce Monitor 2 Comparator Threshold	116.24 V	-404.00	3,616.00
Vce Monitor 3 Comparator Threshold	5.88 V	-404.00	3,616.00
Vce Monitor 4 Comparator Threshold	-404 V	-404.00	3,616.00
Gate Monitor 1 Comparator Threshold	-5.01 V	-15.50	18.80
Gate Monitor 2 Comparator Threshold	-0.03 V	-15.50	18.80
Current Measurement Threshold	0 %	0.00	100.00
di/dt Measurement Threshold	0 %	0.00	100.00
Current Offset Compensation	0 %	0.00	100.00
Series Resistance Compensation	0 %	0.00	100.00
Fibre Drive Current	0 mA	1.82	6.37
Clamp Disable	0	0	1
High Frequency Limit Enable	0	0	1
Test Config Enable	0	0	1
Debug	0	0	15

Change the parameter values by typing them directly into the table or by loading a configuration from a file. Changed parameter values will appear in **red**.

Send the configuration to the gate drive using the buttons below

Apply Config to Gate Drive

Apply this Config to all compatible Gate Drives

Undo all changes

100%

Scan complete. Connection: Virtual (Demo) Mode: Standard

Appendix 4: AV17/AV33/AP0xB Variable Gate Voltage Core (CPLD part number SW000072r06)

Power Insight Configurator

File Help

Connect Disconnect Preferences

AMANTYS PIA v0.9
SW000018r12
R3.9rc2 4 ports

Port 3: GATE DRIVE
PROD_CODE
No serial number

Switching Configuration | Fault Report | Firmware Update | Measurements | Diagnostics

Load from File Save to File Undo Redo Assign Name Update Data File(s) Configure NTC Extract Filesystem Write Filesystem

Name	Value	Min	Max
Gate Turn On Resistor	1.017 Ω	0.47	27.00
Gate Turn Off Resistor	1.527 Ω	1.02	56.00
Gate Soft Turn Off Resistor	12.000 Ω	1.02	56.00
DC Link Measurement Enable	0	0	1
High Vce Gate Turn Off Resistor	5.398 Ω	1.02	56.00
Gate-Emitter Capacitance	0.000 nF	0.00	328.00
Disable Turn-off on Fault	0	0	1
Feedback Protocol	5	0	15
Fault Lock-out Time	100 ms	0.00	64,000.00
Desat Window Time 1	2 μ s	0.00	1,310.00
Desat Window Time 2	2 μ s	0.00	1,310.00
Desat Window Time 3	2 μ s	0.00	1,310.00
Desat Window Time 4	20 μ s	0.00	1,310.00
Gate Monitor 1 Time (ON)	20 μ s	0.00	1,310.00
Gate Monitor 2 Time (OFF)	20 μ s	0.00	1,310.00
Turn On Delay	0 μ s	0.00	5.00
Turn Off Delay	0 μ s	0.00	5.00
Type 2 Short Circuit to Turn Off Delay	0 μ s	0.00	5.00
Vce Monitor Filter Time Constant	1 μ s	0.00	5.00
Desat Diode 1 Enable	12	0	15
Desat Diode 2 Enable	0	0	15
Vce Monitor 1 Enable	0	0	15
Vce Monitor 2 Enable	0	0	15
Vce Monitor 3 Enable	0	0	15
Gate Monitor 1 Enable	1	0	1
Gate Monitor 2 Enable	0	0	1
Desat Diode 1 Comparator Threshold	35.29 V	0.00	35.29
Desat Diode 2 Comparator Threshold	0 V	0.00	35.29
Vce Monitor 1 Comparator Threshold	242.35 V	-404.00	3,616.00
Vce Monitor 2 Comparator Threshold	494.59 V	-404.00	3,616.00
Vce Monitor 3 Comparator Threshold	999.06 V	-404.00	3,616.00
Vce Monitor 4 Comparator Threshold	2102.59 V	-404.00	3,616.00
Gate Monitor 1 Comparator Threshold	10.06 V	-15.50	18.80
Gate Monitor 2 Comparator Threshold	-4.07 V	-15.50	18.80
Current Measurement Threshold	0 %	0.00	100.00
di/dt Measurement Threshold	0 %	0.00	100.00
Current Offset Compensation	0 %	0.00	100.00
Series Resistance Compensation	0 %	0.00	100.00
Fibre Drive Current	4.55 mA	1.82	6.37
Clamp Disable	1	0	1
High Frequency Limit Enable	0	0	1
Variable Gate Voltage Enable	1	0	1
Gate Voltage when ON	15 V	15.00	22.40
Gate Voltage when OFF	-10 V	-10.00	-5.00
Test Config Enable	0	0	1
Debug	0	0	15

Change the parameter values by typing them directly into the table or by loading a configuration from a file. Changed parameter values will appear in **red**

Send the configuration to the gate drive using the buttons below

Apply Config to Gate Drive

Apply this Config to all compatible Gate Drives

Undo all changes

100%

Scanning for device changes... Connection: Console (USB FTDI:Test/1234) Mode: Standard

Appendix 5: AD00XA8 Off-module Gate Drive (CPLD part number SW000094)

Power Insight Configurator

File Help

Connect Disconnect Preferences

AMANTYS PIA v0.9
SW000018r12
R3.9rc2 4 ports

Port 3: GATE DRIVE
AD33AA8P11X-0106
G185000001

Switching Configuration | Fault Report | Firmware Update | Measurements | Diagnostics

Load from File Save to File Undo Redo Assign Name Update Data File(s) Configure NTC Extract Filesystem Write Filesystem

Name	Value	Min	Max
Gate Turn On Resistor	3.900 Ω	0.47	27.00
Gate Turn Off Resistor	3.988 Ω	1.02	56.00
Gate Soft Turn Off Resistor	22.000 Ω	1.02	56.00
DC Link Measurement Enable	0	0	1
High Vce Gate Turn Off Resistor	15.795 Ω	1.02	56.00
Gate-Emitter Capacitance	100.000 nF	0.00	328.00
Disable Turn-off on Fault	0	0	1
Feedback Protocol	5	0	15
Fault Lock-out Time	100 ms	0.00	64,000.00
Desat Window Time 1	5 μs	0.00	1,310.00
Desat Window Time 2	5 μs	0.00	1,310.00
Desat Window Time 3	5 μs	0.00	1,310.00
Desat Window Time 4	20 μs	0.00	1,310.00
Gate Monitor 1 Time (ON)	20 μs	0.00	1,310.00
Gate Monitor 2 Time (OFF)	20 μs	0.00	1,310.00
Turn On Delay	0 μs	0.00	5.00
Turn Off Delay	0 μs	0.00	5.00
Type 2 Short Circuit to Turn Off Delay	0 μs	0.00	5.00
Vce Monitor Filter Time Constant	2 μs	0.00	5.00
Desat Diode 1 Enable	0	0	15
Desat Diode 2 Enable	0	0	15
Vce Monitor 1 Enable	0	0	15
Vce Monitor 2 Enable	0	0	15
Vce Monitor 3 Enable	0	0	15
Gate Monitor 1 Enable	1	0	1
Gate Monitor 2 Enable	0	0	1
Desat Diode 1 Comparator Threshold	35.29 V	0.00	35.29
Desat Diode 2 Comparator Threshold	0 V	0.00	35.29
Vce Monitor 1 Comparator Threshold	494.59 V	-404.00	3,616.00
Vce Monitor 2 Comparator Threshold	999.06 V	-404.00	3,616.00
Vce Monitor 3 Comparator Threshold	1992.24 V	-404.00	3,616.00
Vce Monitor 4 Comparator Threshold	1992.24 V	-404.00	3,616.00
Gate Monitor 1 Comparator Threshold	10.06 V	-15.50	18.80
Gate Monitor 2 Comparator Threshold	-4.07 V	-15.50	18.80
di/dt Monitor 1 Threshold	112	0	255
di/dt Monitor 2 Threshold	120	0	255
di/dt Filter 1 Time Constant	4 μs	0.00	5.00
di/dt Filter 2 Time Constant	4 μs	0.00	5.00
di/dt Enable 1	0	0	1
di/dt Enable 2	0	0	1
Fibre Drive Current	3.64 mA	1.82	6.37
High Frequency Limit Enable	0	0	1
Minimum Pulse Width	50.98 μs	0.00	1,310.00
Minimum Pulse Width Fault Enable	1	0	1
Test Config Enable	0	0	1
Debug	0	0	15

Change the parameter values by typing them directly into the table or by loading a configuration from a file. Changed parameter values will appear in red

Send the configuration to the gate drive using the buttons below

Apply Config to Gate Drive

Apply this Config to all compatible Gate Drives

Undo all changes

100%

Scanning for device changes... Connection: Console (USB FTDI:Test/1234) Mode: Standard